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	Тур	Hits	Search Text	DBs	Time Stamp	Comment	Error Definit ion
H	BRS	Φ	(438/612.ccls. and polymer) and (conductive near polymer)	USPAT	2004/06/0 8 15:53		
2	BRS	48	438/612.ccls. and polymer	USPAT	2001/03/0 9 17:44		
ω	BRS	2053	semiconductor near carrier	USPAT; EPO; JPO; DERWENT; IBM_TDB	2001/03/1 2 12:42		
4	BRS	0	(semiconductor near carrier) and membrane and (conductive near polymer)	USPAT; EPO; JPO; DERWENT; IBM_TDB	2001/03/0 9 17 : 54		
U	BRS	22	(semiconductor near carrier) and membrane	USPAT; EPO; JPO; DERWENT; IBM_TDB	2001/03/0 9 17:48		

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BRS	BRS	BRS	Тур
	O	U	Hits
(soldr near bump\$) and (conduct\$ near polymer)	(semiconductor near carrier) and (conductive near polymer)	(((semiconductor near carrier) and membrane) and polymer) and conduct\$	Search Text
USPAT; EPO; JPO; DERWENT; IBM_TDB	USPAT; EPO; JPO; DERWENT; IBM_TDB	USPAT; EPO; JPO; DERWENT; IBM_TDB	DBs
2001/03/0 9 17 : 57	2001/03/0 9 17:56	2001/03/0 9 17:48	Time Stamp
			Comment
Truncat ion Overflo w. Return string from Server is: 5`9`11` SO		Truncat ion Overflo w. Return string from Server is: 5`0`0`C	Error Definit ion

ion ion Overflo W. Return string from Server is: 5`0`0`C ON	2001/03/1 2 15:11	USPAT	((semiconductor near carrier) and gold) and (conduct\$ adj polymer)	ω	BRS	14
3	2001/03/1 2 15:16	USPAT	(semiconductor near carrier) and gold	211	BRS	13
	2001/03/1 2 15:16	USPAT	438/118,119,613,614,65 0.ccls. and (conductive near polymer)	32	BRS	12
	2001/03/1 2 16:25	USPAT	438/118,119,613,614,65 0.ccls.	1065	BRS	11
	2001/03/1 2 12:43	USPAT; EPO; JPO; DERWENT; IBM_TDB	(semiconductor near carrier) and membrane and polymer	6	BRS	10
	2001/03/1	USPAT; EPO; JPO; DERWENT; IBM_TDB	semiconductor near carrier	2057	BRS	9
Comment Definit	Time Stamp	DBs	Search Text	Hits	Тур	-

	Тур	Hits	Search Text	DBs	Time Stamp	Comment	Error Definit ion
17 5	BRS	4539	semiconductor near (carrier or carrier or assembly)	USPAT; EPO; JPO; DERWENT; IBM_TDB	2001/03/1 2 15:14		
16	BRS	601	(semiconductor near (carrier or carrier or carrier or lassembly)) and gold	USPAT	2001/03/1 2 15:16		
17	BRS	28	((semiconductor near (carrier or carrier or assembly)) and gold) and (conductive near polymer)	USPAT	2001/03/1 2 16:01		
18	BRS	441	epoxy near5 (bump or ball)	USPAT; EPO; JPO; DERWENT; IBM_TDB	2001/03/1 2 16:02		
19	BRS	20	(epoxy near5 (bump or ball)) and (conductive near polymer)	USPAT; EPO; JPO; DERWENT; IBM_TDB	2001/03/1 2 16:03		
20	BRS	1220	257/737,738,778.ccls.	USPAT	2001/03/1 2 16:25		
21	BRS	3 ₁	257/737,738,778.ccls. and (epoxy near5 (bump or ball))	USPAT	2001/03/1 2 18:28		
22	BRS	570	228/180.22.ccls.	USPAT	2001/03/1 2 16:49		

	Тур	Hits	Search Text	DBs	Time Stamp	Comment	Error Definit ion
23	BRS	13	228/180.22.ccls. and (epoxy near5 (bump or ball))	USPAT	2001/03/1 2 16:50		
24	BRS	7	(semiconductor near (carrier or carrier or carrier or assembly)) and (gold near ball)	USPAT	2001/03/1 2 18:29		
25	BRS	0	((semiconductor near carrier) and membrane) and polymer	USPAT; EPO; JPO; DERWENT; IBM_TDB	2001/03/1 3 11:18		
26	BRS	1825	bump same (carrier or interposer) same chip	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2001/06/1 3 17:57		
27	BRS	66	(bump same (carrier or interposer) same chip) same (alternative\$ or interchange\$)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2001/06/1 3 18:47		
28	IS& R	}	("4875617").PN.	USPAT	2001/06/1 3 18:47		
29	IS& R	⊢-	("6376352").PN.	USPAT	2004/06/0 8 11:14		

	Тур	Hits	Search Text	DBs	Time Stamp	Comment I	Error Definit ion
30	BRS	4723	compliant and epoxy	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/0 8 11:14		
31	BRS	412	compliant with epoxy	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/0 8 11:15		
32	BRS	207	(compliant with epoxy) and semiconductor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/0 8 11:15		
$\frac{\omega}{\omega}$	BRS	57	((compliant with epoxy) and semiconductor) and BGA	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/0 8 11:26		
34	BRS	95	bump with epoxy with coat\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/0 8 11:26		